LVCMOS/LVTTL CLOCK DIVIDER

ICS87001-01

General Description

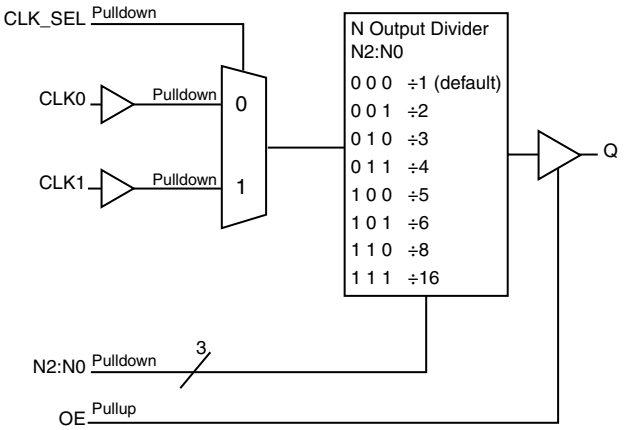
The ICS87001-01 is a low skew, ÷1, ÷2 ÷3, ÷4 ÷5, ÷6 ÷8, ÷16 LVCMOS/LVTTL Fanout Buffer/Divider and a member of theHiPerClockS™ family of High Performance Clock Solutions from IDT. The ICS87001-01 has selectable clock inputs that accept single ended input levels. Output enable pin controls whether the output is in the active or high impedance state.

The ICS87001-01 is characterized at 3.3V, 2.5V and mixed 3.3V/2.5V, 3.3V/1.8V, 2.5V/1.8V input/output supply operating modes.Guaranteed part-to-part skew characteristics make the ICS87001-01 ideal for those applications demanding well defined performance and repeatability.

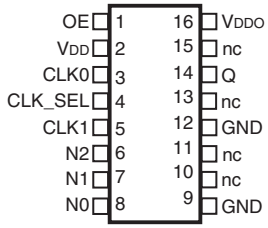
Features

- One LVCMOS / LVTTL output, 15Ω output impedance
- Selectable LVCMOS / LVTTL clock inputs
- Maximum output frequency: 250MHz
- Part-to-part skew: TBD
- Power supply modes:
  Core/Output
  3.3V/3.3V
  3.3V/2.5V
  3.3V/1.8V
  2.5V/2.5V
  2.5V/1.8V
- 0°C to 70°C ambient operating temperature
- Available in both standard (RoHS 5) and lead-free (RoHS 6) packages

Block Diagram



Pin Assignment



ICS87001-01
16-Lead TSSOP
4.4mm x 3.0mm x 0.925mm
package body
G Package
Top View

The Preliminary Information presented herein represents a product in pre-production. The noted characteristics are based on initial product characterization and/or qualification. Integrated Device Technology, Incorporated (IDT) reserves the right to change any circuitry or specifications without notice.

Table 1. Pin Descriptions

Number	Name	Type		Description
1	OE	Input	Pullup	Output enable. When LOW, outputs are in HIGH impedance state. When HIGH, outputs are active. LVCMOS / LVTTL interface levels.
2	V_{DD}	Power		Power supply pin.
3, 5	CLK0, CLK1	Input	Pulldown	Single-ended clock input. LVCMOS/LVTTL interface levels.
4	CLK_SEL	Input	Pulldown	Clock select input. When HIGH, selects CLK1 input. When LOW, selects CLK0 input. LVCMOS / LVTTL interface levels.
6, 7, 8	N2, N1, N0	Input	Pulldown	N divider pins. LVCMOS/LVTTL interface levels. See Table 3.
9, 12	GND	Power		Power supply ground.
10, 11, 13, 15	nc	Unused		No connect.
14	Q	Output		Single-ended clock output. 15Ω output impedance. LVCMOS/LVTTL interface levels.
16	V_{DDO}	Power		Output supply pin.

NOTE: *Pullup and Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics,* for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance			4		pF
R_{PULLUP}	Input Pullup Resistor			51		kΩ
$R_{PULLDOWN}$	Input Pulldown Resistor			51		kΩ
C_{PD}	Power Dissipation Capacitance			10		pF
R_{OUT}	Output Impedance			15		Ω

Function Tables

Table 3. Programmable Output Divider Function Table

Inputs			N Divider Value	Output Frequency (MHz)
N2	N1	N0		
0	0	0	÷1 (default)	250
0	0	1	÷2	125
0	1	0	÷3	83.333
0	1	1	÷4	62.5
1	0	0	÷5	50
1	0	1	÷6	41.667
1	1	0	÷8	31.25
1	1	1	÷16	15.625

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics or AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{CC}	4.6V
Inputs, V_I	-0.5V to V_{DD} + 0.5V
Outputs, V_O	-0.5V to V_{DDO}+ 0.5V
Package Thermal Impedance, θ_{JA}	100.3°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, V_{DD} = V_{DDO} = 3.3V ± 5%,T_A = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current			40		mA
I_{DDO}	Output Supply Current			1		mA

Table 4B. Power Supply DC Characteristics, V_{DD} = 3.3V ± 5%, V_{DDO} =2.5V ± 5%, T_A = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current			40		mA
I_{DDO}	Output Supply Current			1		mA

Table 4C. Power Supply DC Characteristics, V_{DD} = 3.3V ± 5%, V_{DDO} =1.8V ± 0.15V, T_A = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		1.65	1.8	1.95	V
I_{DD}	Power Supply Current			40		mA
I_{DDO}	Output Supply Current			1		mA

Table 4D. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = 0°C$ to $70°C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current			39		mA
I_{DDO}	Output Supply Current			1		mA

Table 4E. Power Supply DC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.15V$, $T_A = 0°C$ to $70°C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		1.65	1.8	1.95	V
I_{DD}	Power Supply Current			39		mA
I_{DDO}	Output Supply Current			1		mA

Table 4F. LVCMOS/LVTTL DC Characteristics, $T_A = 0°C$ to $70°C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage		$V_{DD} = 3.465V$	2		$V_{DD} + 0.3$	V
			$V_{DD} = 2.625V$	1.7		$V_{DD} + 0.3$	V
V_{IL}	Input Low Voltage		$V_{DD} = 3.465V$	-0.3		0.8	V
			$V_{DD} = 2.625V$	-0.3		0.7	V
I_{IH}	Input High Current	CLK0, CLK1, N[2:0], CLK_SEL	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			150	µA
		OE	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			5	µA
I_{IL}	Input Low Current	CLK0, CLK1, N[2:0], CLK_SEL	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-5			µA
		OE	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-150			µA
V_{OH}	Output High Voltage; NOTE 1		$V_{DDO} = 3.3V \pm 5\%$	2.6			V
			$V_{DDO} = 2.5V \pm 5\%$	1.8			V
			$V_{DDO} = 1.8V \pm 0.15V$	1.5			V
V_{OL}	Output Low Voltage; NOTE 1		$V_{DDO} = 3.3V \pm 5\%$			0.5	V
			$V_{DDO} = 2.5V \pm 5\%$			0.5	V
			$V_{DDO} = 1.8V \pm 0.15V$			0.4	V
I_{OZL}	Output Hi-Z Current Low			-5			µA
I_{OZH}	Output Hi-Z Current High					5	µA

NOTE 1: Outputs terminated with 50Ω to $V_{DDO}/2$. See Parameter Measurement Information, *Output Load Test Circuit diagrams.*

AC Electrical Characteristics

Table 5A. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = 0°C$ to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1			4.3		ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3					ps
t_R / t_F	Output Rise/Fall Time; NOTE 4	20% to 80%		700		ps
odc	Output Duty Cycle			50		%
t_{EN}	Output Enable Time; NOTE 4				5	ns
t_{DIS}	Output Disable Time; NOTE 4				5	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f \leq 250$MHz unless noted otherwise.
NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.
NOTE 2: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 4: This parameters are guaranteed by characterization. Not tested in production.

Table 5B. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0°C$ to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1			4.6		ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3					ps
t_R / t_F	Output Rise/Fall Time; NOTE 4	20% to 80%		800		ps
odc	Output Duty Cycle			50		%
t_{EN}	Output Enable Time; NOTE 4				5	ns
t_{DIS}	Output Disable Time; NOTE 4				5	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f \leq 250$MHz unless noted otherwise.
NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.
NOTE 2: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 4: This parameters are guaranteed by characterization. Not tested in production.

Table 5C. AC Characteristics, V_{DD} = 3.3V ± 5%, V_{DDO} = 1.8V ± 0.15V, T_A = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1			5		ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3					ps
t_R / t_F	Output Rise/Fall Time; NOTE 4	20% to 80%		1		ns
odc	Output Duty Cycle			50		%
t_{EN}	Output Enable Time; NOTE 4				5	ns
t_{DIS}	Output Disable Time; NOTE 4				5	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f \leq$ 250MHz unless noted otherwise.
NOTE 1: Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
NOTE 2: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions. Using the same type of input on each device, the output is measured at V_{DDO}/2.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 4: This parameters are guaranteed by characterization. Not tested in production..

Table 5D. AC Characteristics, V_{DD} = V_{DDO} = 2.5V ± 5%, T_A = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1			4.7		ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3					ps
t_R / t_F	Output Rise/Fall Time; NOTE 4	20% to 80%		900		ps
odc	Output Duty Cycle			50		%
t_{EN}	Output Enable Time; NOTE 4				5	ns
t_{DIS}	Output Disable Time; NOTE 4				5	ns

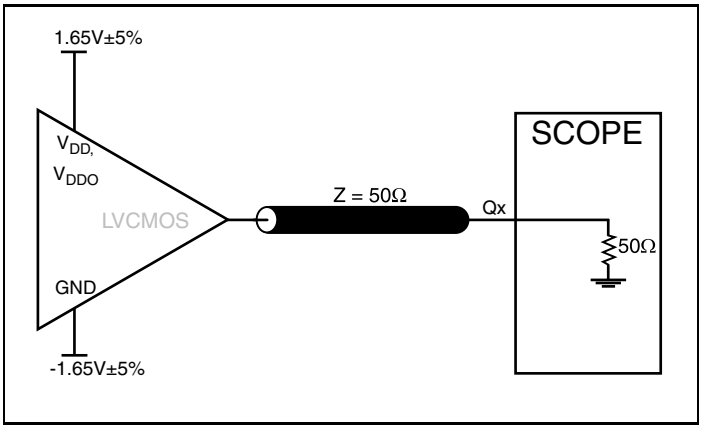
NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f \leq$ 250MHz unless noted otherwise.
NOTE 1: Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
NOTE 2: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions. Using the same type of input on each device, the output is measured at V_{DDO}/2.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 4: This parameters are guaranteed by characterization. Not tested in production.

Table 5E. AC Characteristics, V_{DD} = 2.5V ± 5%, V_{DDO} = 1.8V ± 0.15V, T_A = 0°C to 70°C

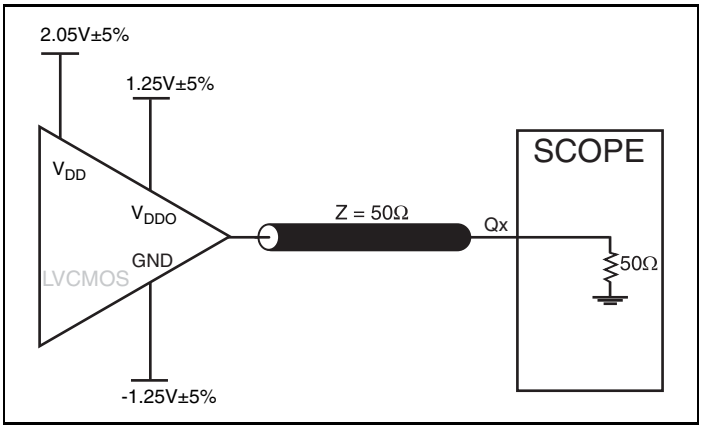
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1			5		ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3					ps
t_R / t_F	Output Rise/Fall Time; NOTE 4	20% to 80%		1.1		ns
odc	Output Duty Cycle			50		%
t_{EN}	Output Enable Time; NOTE 4				5	ns
t_{DIS}	Output Disable Time; NOTE 4				5	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f \leq$ 250MHz unless noted otherwise.
NOTE 1: Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
NOTE 2: Defined as skew between outputs on different devices operating a the same supply voltage and with equal load conditions. Using the same type of input on each device, the output is measured at V_{DDO}/2.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 4: This parameters are guaranteed by characterization. Not tested in production.

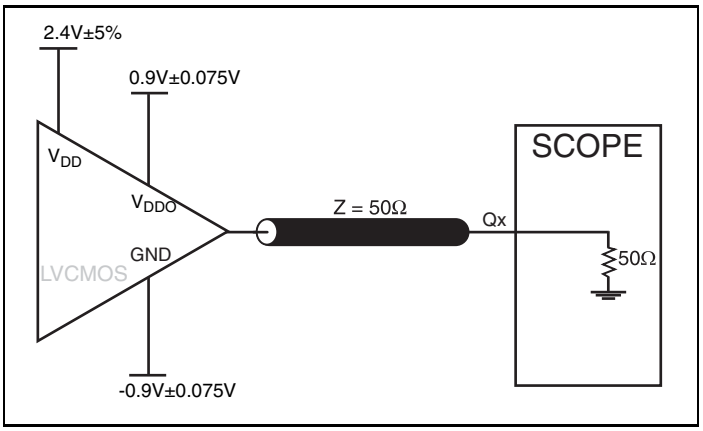
Parameter Measurement Information



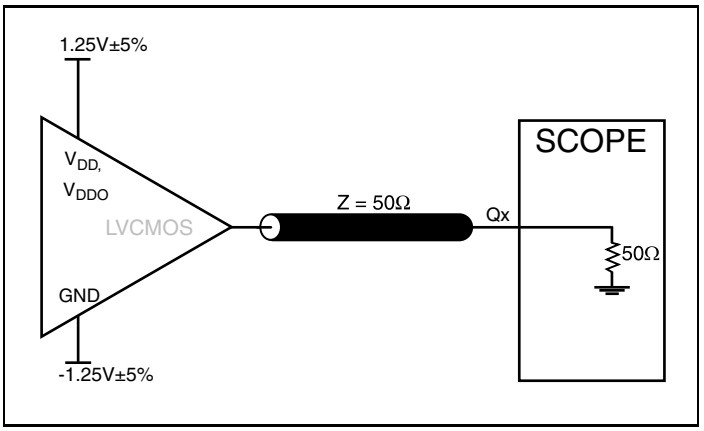
3.3V Core/3.3V LVCMOS Output Load AC Test Circuit



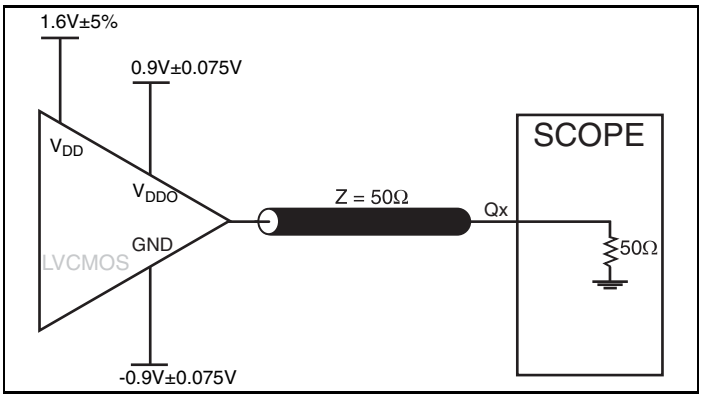
3.3V Core/2.5V LVCMOS Output Load AC Test Circuit



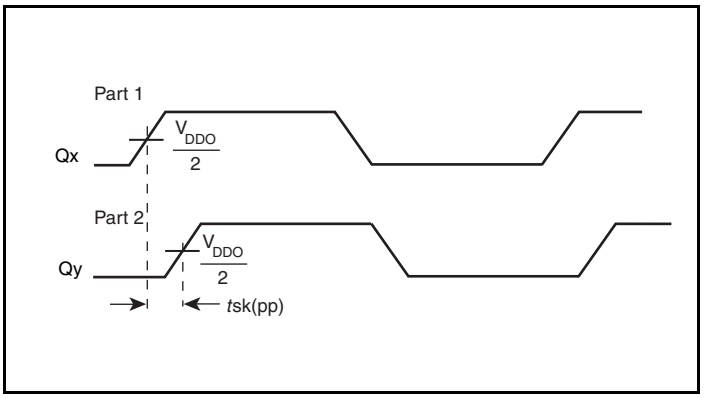
3.3V Core/1.8V LVCMOS Output Load AC Test Circuit



2.5V Core/2.5V LVCMOS Output Load AC Test Circuit

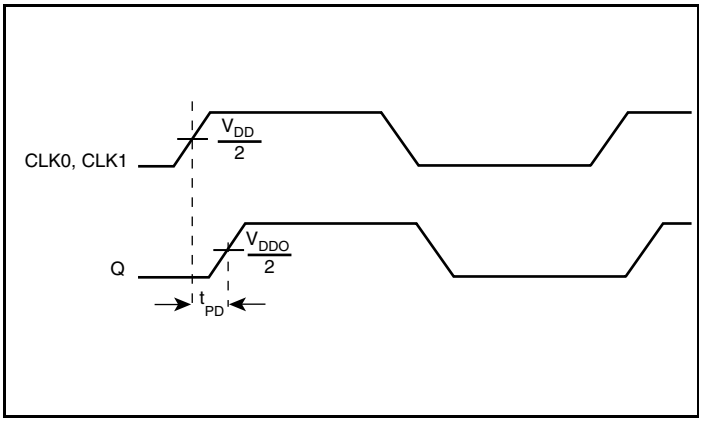


2.5V Core/1.8V LVCMOS Output Load AC Test Circuit

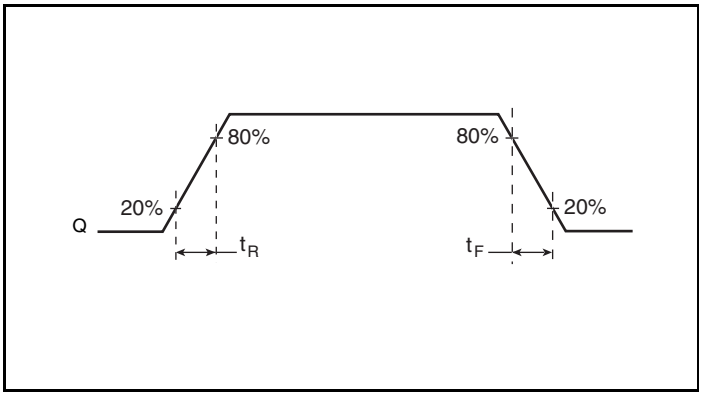


Part-to-Part Skew

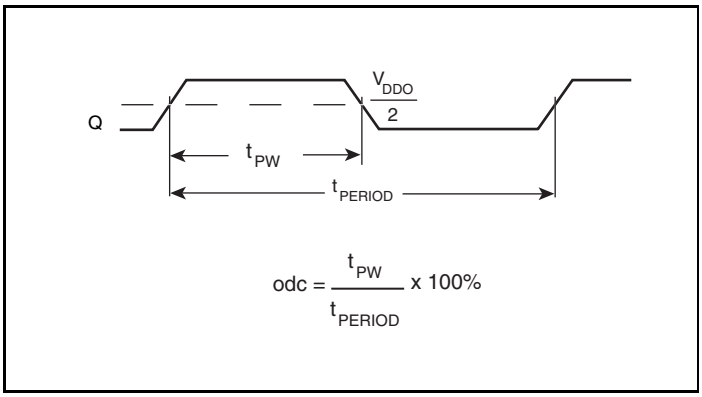
Parameter Measurement Information, continued



Propagation Delay



Output Rise/Fall Time



Output Duty Cycle/Pulse Width/Period

Application Information

Recommendations for Unused Input Pins

Inputs:

LVCMOS Control Pins

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A 1kΩ resistor can be used.

CLK Inputs

For applications not requiring the use of a clock input, it can be left floating. Though not required, but for additional protection, a 1kΩ resistor can be tied from the CLK input to ground.

Reliability Information

Table 6. θ_{JA} vs. Air Flow Table for a 16 Lead TSSOP

θ_{JA} vs. Air Flow			
Meters per Second	**0**	**1**	**2.5**
Multi-Layer PCB, JEDEC Standard Test Boards	100.3°C/W	96.0°C/W	93.9°C/W

Transistor Count

The transistor count for ICS87001-01: 2781

Package Outline and Package Dimensions

Package Outline - G Suffix for 16 Lead TSSOP

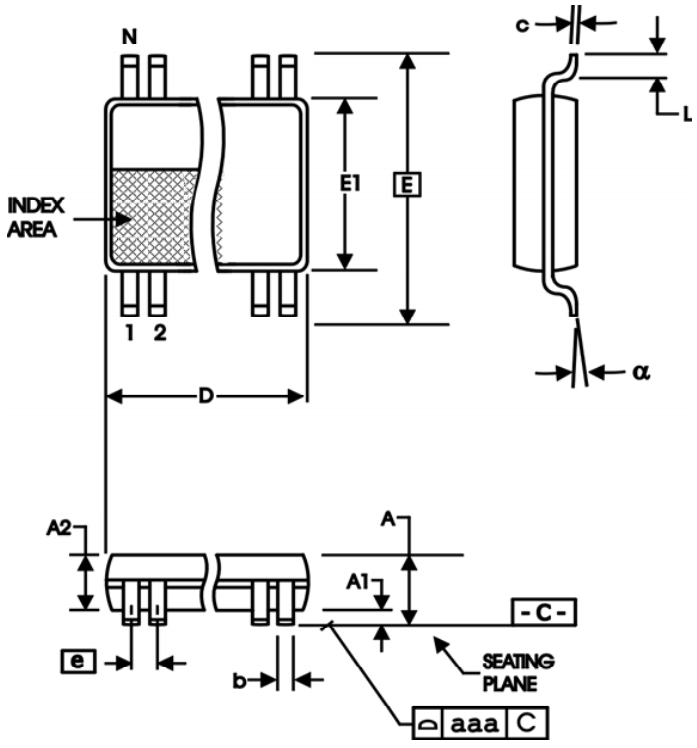


Table 7. Package Dimensions for 16 Lead TSSOP

All Dimensions in Millimeters		
Symbol	**Minimum**	**Maximum**
N	16	
A		1.20
A1	0.5	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E	6.40 Basic	
E1	4.30	4.50
e	0.65 Basic	
L	0.45	0.75
α	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
87001BG-01	87001B01	16 Lead TSSOP	Tube	0°C to 70°C
87001BG-01T	87001B01	16 Lead TSSOP	2500 Tape & Reel	0°C to 70°C
87001BG-01LF	7001B01L	“Lead-Free” 16 Lead TSSOP	Tube	0°C to 70°C
87001BG-01LFT	7001B01L	“Lead-Free” 16 Lead TSSOP	2500 Tape & Reel	0°C to 70°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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